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General Description:

A gallium arsenide infrared emitting diode combined with a silicon photo detector; bilateral analog fet output; 2500v peak isolation voltage; 6-pin dip; 0.344 in. Lg; 0.25 in. W; 0.125 in. H

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A23900